

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Chip-Scale Package (CSP).

2. Features and benefits

- Average forward current I_{F(AV)} ≤ 0.2 A
- Reverse voltage V_R ≤ 30 V
- Low forward voltage typ. V_F = 310 mV
- Low reverse current typ. I_R = 0.33 μA
- Package height typ. 0.3mm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Ultra high speed switching
- LED backlight for mobile application

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; T _{amb} ≤ 140 °C; square wave	[1]	-	-	0.2	A
		δ = 0.5; f = 20 kHz; T _{sp} ≤ 148 °C; square wave		-	-	0.2	A
V _R	reverse voltage	T _j = 25 °C		-	-	30	V
V _F	forward voltage	I_F = 10 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C		-	310	390	mV
I _R	reverse current	V_R = 10 V; T_j = 25 °C; pulsed		-	0.33	2	μA
t _{rr}	reverse recovery time	I _F = 500 mA; I _R = 500 mA; I _{R(meas)} = 100 mA; T _j = 25 °C		-	1.42	-	ns





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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode[1]		1 🕂 2
2	А	anode	1 2	sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
PMEG3002ESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2					

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMEG3002ESF	К

30 V, 0.2 A low VF MEGA Schottky barrier rectifier

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _R	reverse voltage	T _j = 25 °C		-	30	V
l _F	forward current	T _{sp} ≤ 145 °C; δ = 1		-	0.28	А
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; T _{amb} ≤ 140 °C; square wave	[1]	-	0.2	A
		δ = 0.5; f = 20 kHz; T _{sp} ≤ 148 °C; square wave		-	0.2	A
I _{FRM}	repetitive peak forward current	t _p = 1 ms; δ ≤ 0.25		-	1.5	А
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	3.5	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	405	mW
			[3]	-	660	mW
			[1]	-	1200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

9. Thermal characteristics

Table 6.Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1][2]	-	-	310	K/W
	from junction to ambient		[1][3]	-	-	190	K/W
	ambient		[1][4]	-	-	105	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	40	K/W

 For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

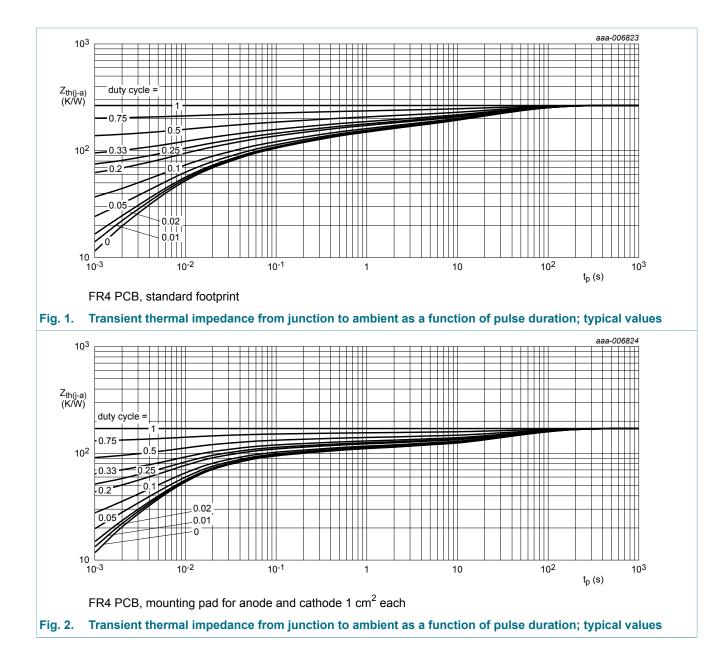
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of anode tab.

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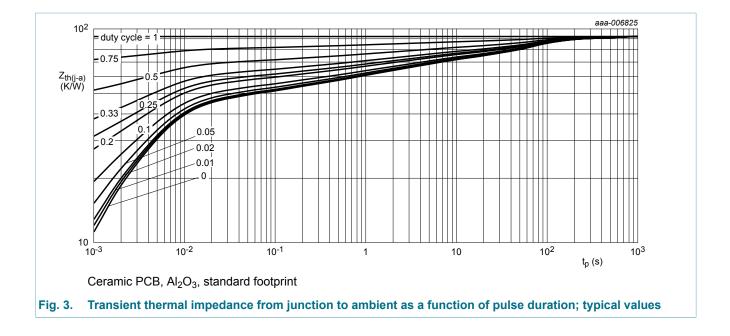
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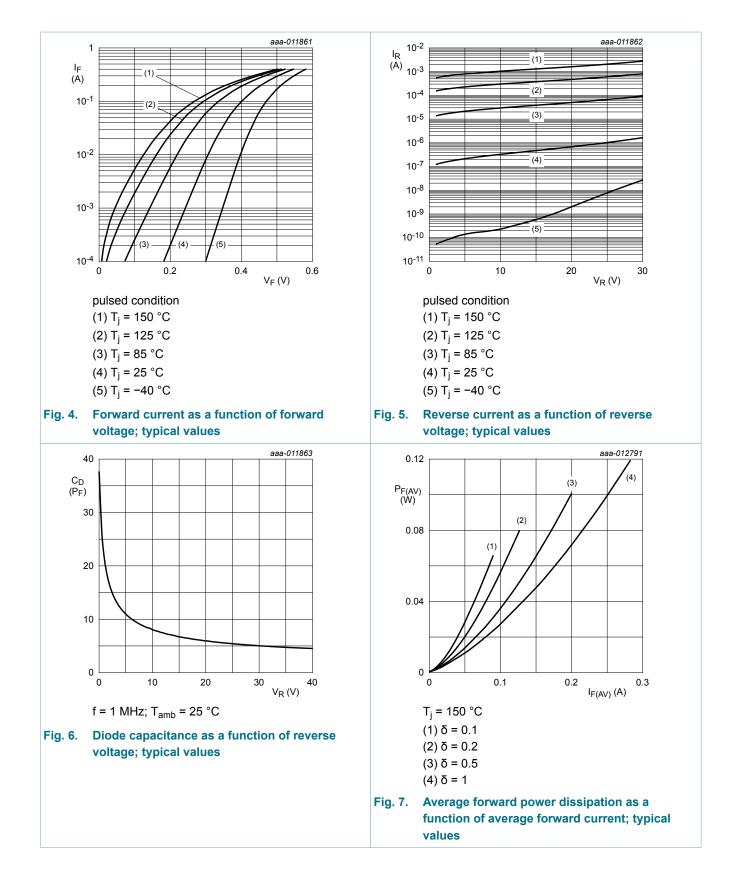
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)R}	reverse breakdown voltage	I _R = 100 μA; t _p = 300 μs; δ = 0.02; T _j = 25 °C	30	-	-	V
VF	forward voltage	I _F = 0.1 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	185	255	mV
		I_F = 1 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	245	320	mV
		I _F = 10 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	310	390	mV
		I _F = 100 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	405	480	mV
		I _F = 200 mA; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	460	535	mV
I _R	reverse current	V_{R} = 10 V; T _j = 25 °C; pulsed	-	0.33	2	μA
		V_{R} = 30 V; T _j = 25 °C; pulsed	-	1.8	9	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	21	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	8	-	pF
t _{rr}	reverse recovery time	I _F = 500 mA; I _R = 500 mA; I _{R(meas)} = 100 mA; T _j = 25 °C	-	1.42	-	ns

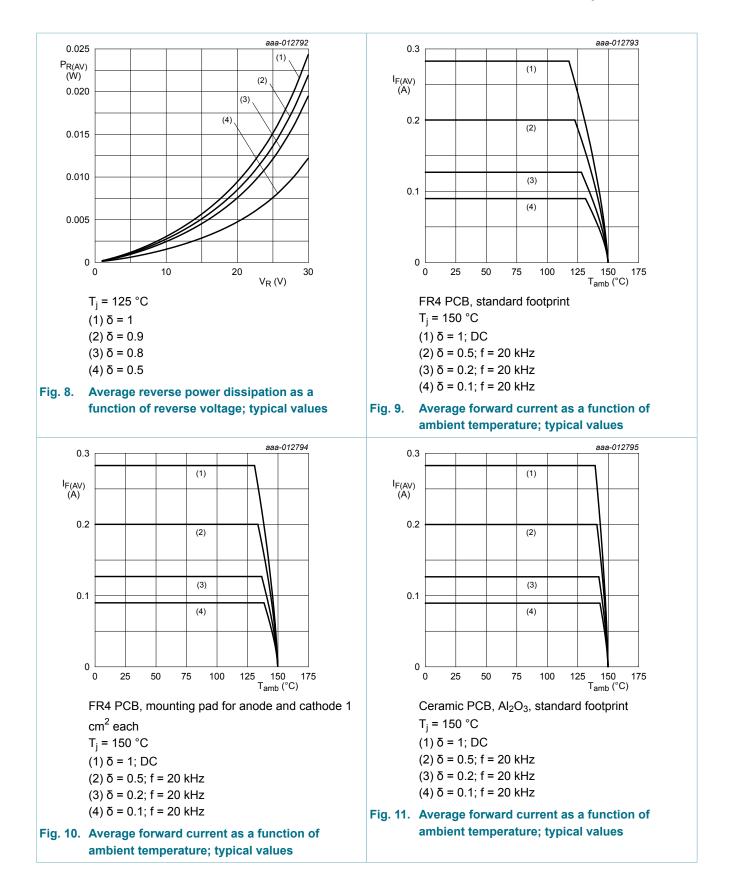
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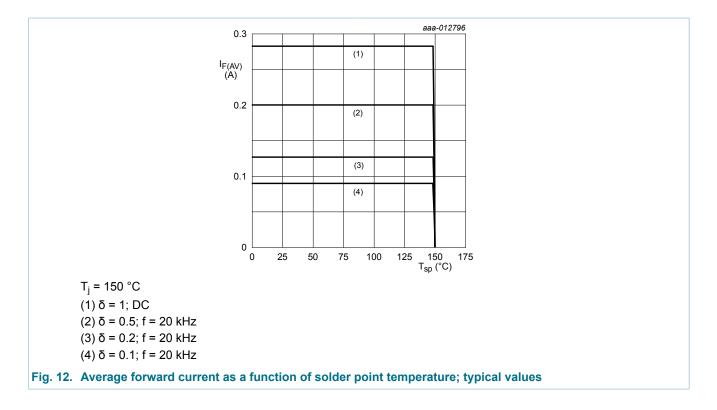
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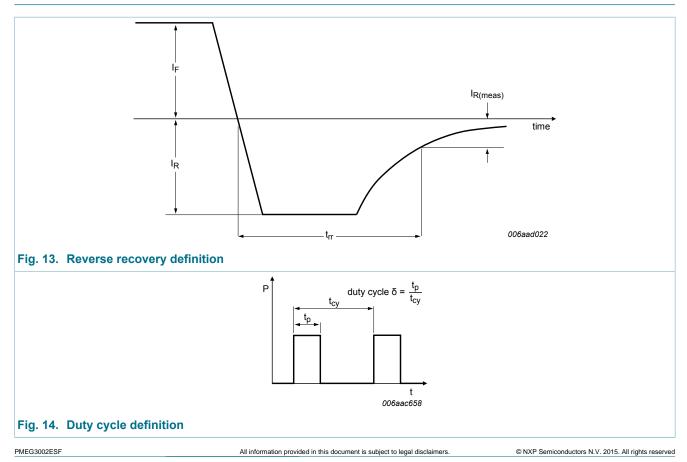
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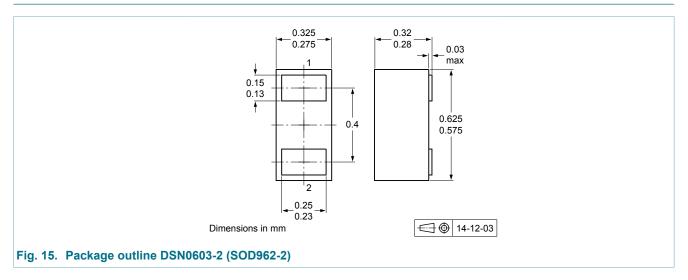
11. Test information



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The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

12. Package outline



13. Soldering

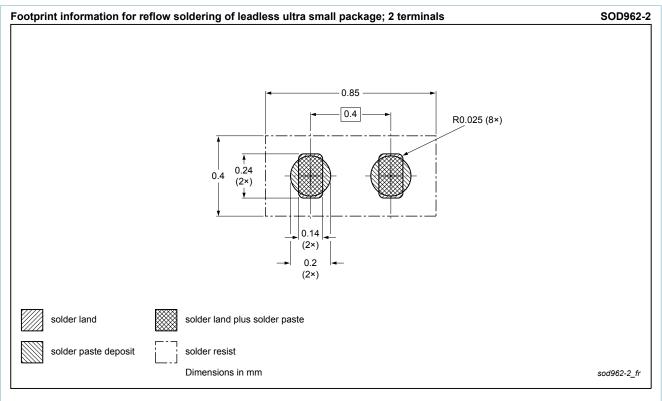


Fig. 16. Reflow soldering footprint for DSN0603-2 (SOD962-2)

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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMEG3002ESF v.2	20150217	Product data sheet	-	PMEG3002ESF v.1			
Modifications:	Product status char	nged					
PMEG3002ESF v.1	20140415	Preliminary data sheet	-	-			

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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30 V, 0.2 A low VF MEGA Schottky barrier rectifier

16. Contents

General description	1
Features and benefits	1
Applications	1
Quick reference data	1
Pinning information	2
Ordering information	2
Marking	2
Limiting values	3
Thermal characteristics	3
Characteristics	6
Test information	9
Package outline	10
Soldering	10
Revision history	11
Legal information	12
Data sheet status	
Definitions	12
Disclaimers	12
Trademarks	13
	Features and benefits

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